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| PTO/SB/08A | | Complete if Known | |
| INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary) | | Application Number | 09/366,850 |
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| | | Confirmation Number | 3575 |
| | | First Named Inventor | Robert J. Falster |
| | | Group Art Unit | 2811 |
| | | Examiner Name | Donghee Kang |
| Sheet 1 of 1 | Attorney Docket No. | MEMC 98-0410 (2489) | |

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| U.S. PATENT DOCUMENTS | | | | | | | |
|---|-----------------------|--|--------------------------------------|---|---|---|----------------|
| Examiner Initials* | Cite No. ¹ | U.S. Patent Document | | Name of Patentee or Applicant of Cited Document | Date of Publication of Cited Document MM-DD-YYYY | | |
| | | Number | Kind Code ² (if known) | | | | |
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| FOREIGN PATENT DOCUMENTS | | | | | | | |
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| DM | 63 | DENG, B. et al., "Uniformalization of the Pt-Induced-Trip Concentration Profile in Silicon by the Two-Step Diffusion Method," Semicond. Sci. Technol., Vol. 11, pp. 535-537, 1996 | | | | | |

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| Examiner Signature | <i>Kang Donghee</i> | Date Considered | 12-03-03 |
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